

FEATURES

- Up to 3,000,000 usable equivalent gates using standard cell architecture
- Toggle rates up to 1.2 GHz
- Advanced 0.25 μ silicon gate CMOS processed in a commercial fab
- Operating voltage of 100% 3.3V or 3.3V I/O and 2.5V core
- Input buffers are 5-volt tolerant
- Multiple product assurance levels available, QML V and Q, military, industrial
- Radiation hardened from 100 krad(Si) to 1 Mrad total dose available using Aeroflex's RadHard techniques
- SEU-immune to less than 1.0E-10 errors/bits-day available using special library cells
- Robust Aeroflex Design Library of cells and macros
- Support for Verilog and VHDL design languages on Sun and Linux workstations
- Cell models validated in Mentor Graphics® and Synopsys™ design environments
- Full complement of industry standard IP cores
- Various RAM configurations available
- Supports cold sparing for power down applications
- Power dissipation of 0.04 μ W/MHz/gate at V_{DDCORE} 2.5V and 20% duty cycle and 0.06 μ W/MHz/gate at V_{DDCORE} 3.3V and 20% duty cycle
- External chip capacitor attachment option available to space quality levels (for improved SSO response)

PRODUCT DESCRIPTION

The high-performance UT0.25um Hardened-by-Design ASIC standard cell family features densities up to 3,000,000 equivalent gates and is available in multiple quality assurance levels such as MIL-PRF-38535, QML V and Q, military, industrial grades, and non-RadHard versions.

For those designs requiring stringent radiation hardness, Aeroflex's 0.25um process employs a special technique that enhances the total dose radiation hardness from 100Krad(Si) to 1 Mrad while maintaining circuit density and reliability. In addition, for greater transient radiation hardness and latch-up immunity, the deep submicron process is built on epitaxial wafers.

Developed from Aeroflex's patented architectures, the 0.25um ASIC family uses a highly efficient standard cell architecture for internal cell instantiation. Combined with state-of-the-art, timing driven placement and routing tools, the area utilization and signal routing of transistors is maximized using five levels of metal interconnect.

The UT0.25uHBD ASIC family is supported by an extensive cell library that includes SSI, MSI, and 54XX equivalent functions, as well as PLL, RAM, and cores. Aeroflex's core library includes the following functions:

- Intel 80C31® equivalent
- Intel 80C196® equivalent
- MIL-STD-1553 functions (BRCTM, RTI, RTMP)
- MIL-STD-1750 microprocessor
- RISC microcontroller
- Select RAM configurations (with optional MBIST and EDAC)
- Phase Locked Loop (PLL)
- Aeroflex Gaisler - LEON3 and other IP can be reviewed at www.gaisler.com/CMS

Table 1. Gate Densities

DIE SIZE (Mils estimate)	EQUIVALENT USABLE GATES¹	SIGNAL I/O²	POWER & GROUND PADS
245	276,890	160	48
313	501,760	216	64
374	757,350	265	79
426	1,024,000	308	92
510	1,524,122	376	112
578	2,007,040	431	129
642	2,524,058	484	144
699	3,029,402	530	158

Notes:

1. Based on NAND2 equivalents plus 20% routing overhead. Actual usable gate count is design-dependent.

Low-noise Device and Package Solutions

Separate on-chip power and ground buses are provided for internal cells and output drivers which further isolate internal design circuitry from switching noise.

In addition, Aeroflex offers advanced low-noise package technology with multi-layer, co-fired ceramic construction featuring built-in isolated power and ground planes (see Table 2). These planes provide lower overall resistance/inductance through power and ground paths which minimize voltage drops during periods of heavy switching. These isolated planes also

help sustain supply voltage during dose rate events, thus preventing rail span collapse.

Flatpacks are available with up to 352 leads; PGAs are available with up to 299 pins and LGAs/CCGAs to 624 pins. Aeroflex's flatpacks feature a non-conductive tie bar that helps maintain lead integrity through test and handling operations. In addition to the packages listed in Table 2, Aeroflex offers custom package development and package tooling modification services for individual requirements.

Table 2. Packages

Type	Package
Flatpack	68, 84, 132, 172, 196, 208, 240, 256, 304, 352
PGA	299
LGA ⁴	472, 624

Notes:

- 1. Contact Aeroflex for specific package drawings.
- 2. External chip capacitor attachment option available to space quality levels (for improved SSO response).
- 3. Aeroflex supports all JEDEC outline package designs. Listed packages are tooled.
- 4. LGA package formats can be provided with Solder Columns.

Extensive Cell Library

The UT0.25uHBD standard cell family is supported by an extensive cell library that includes SSI, MSI, and 54XX-equivalent functions, as well as RAM and other library functions. User-selectable options for cell configurations include scan and radiation hardness (SEU) levels for all register elements, as well as output drive strength. Phase-Locked Loop (PLL) macro cells are derived from the Aeroflex Standard Products UT7R995 RadClock™. They are available in three frequency ranges - 24MHz to 50MHz, 48MHz to 100MHz, and 96MHz to 200MHz. All PLLs support a power-down mode and phase lock indicator.

Refer to Aeroflex's UT0.25uHBD Design Manual for complete cell listing and details.

I/O Buffers

The UT0.25uHBD gate array family offers up to 530 signal I/O locations (note: device signal I/O availability is affected by package selection and pinout). The I/O cells can be configured by the user to serve as input, output, bidirectional, three-state, or additional power and ground pads. Output drive options range from 4 to 24mA. To drive larger off-chip loads, output drivers may be combined in parallel to provide additional drive up to 48mA.

Other I/O buffer features and options include:

- Pull-up and pull-down resistors
- Schmitt trigger
- LVDS
- PCI
- SSTL
- CML
- Cold Sparing

LVDS transmitter (Tx) and receiver (Rx) buffers are based on the Aeroflex Standard Products UT54LVDS031LV LVDS driver and UT54LVDS032LV receiver products. They provide the same >400Mbps (200MHz) switching rates, 340mV nominal differential signaling levels, cold-sparing, transmitter enable, and receiver fail-safe circuitry. Each supports a power-down mode, putting the I/O buffers into their lowest power state. A unique Aeroflex reference circuit improves performance matching between multiple Tx buffers and multiple Rx buffers.

The PCI I/O buffer is usable as an input, output or bidirect and is compliant to the PCI 2.2 specification.

Aeroflex's ASIC SSTL bidirect, tristate, and input buffers are based on the JESD8-15A standard for Stub Series Terminated Logic for 1.8V (SSTL_18) Class-1 and -2. They provide switching rates >200Mbps (100MHz) and all support a power-down mode.

JTAG Boundary-Scan

The UT0.25uHBD arrays provide for a test access port and boundary-scan that conforms to the IEEE Standard 1149.1 (JTAG). Some of the benefits of this capability are:

- Easy test of complex assembled printed circuit boards
- Gain access to and control of internal scan paths
- Initiation of Built-In Self Test

Clock Driver Distribution

Aeroflex design tools provide methods for balanced clock distribution that maximize drive capability and minimize relative clock skew between clocked devices.

Speed and Performance

Aeroflex specializes in high-performance circuits designed to operate in harsh military and radiation environments. Table 3 presents a sampling of typical cell delays.

Note that the propagation delay for a CMOS device is a function of its fanout loading, input slew, supply voltage, operating temperature, and processing radiation tolerance. In a radiation environment, additional performance variances must be considered.

The UT0.25uHBD array family simulation models account for all of these effects to accurately determine circuit performance for its particular set of use conditions.

Power Dissipation

Each internal gate or I/O driver has an average power consumption based on its switching frequency and capacitive loading. Radiation-tolerant processes exhibit power dissipation that is typical of CMOS processes. For a rigorous power estimating methodology, refer to the Aeroflex UT0.25uHBD Design Manual or consult with a Aeroflex Applications Engineer.

Typical Power Dissipation

0.04μW/Gate-MHz@2.5V	20% duty cycle
0.06μW/Gate-MHz@3.3V	20% duty cycle

Table 3. Typical Cell Delays

CELL	OUTPUT TRANSITION	PROPAGATION DELAY ¹	PROPAGATION DELAY ¹
Internal Gates		V_{DD} = 2.5V	V_{DD} = 3.3V
INV1, Inverter	HL	.123	.150
	LH	.155	.230
INV4, Inverter 4X	HL	.077	.104
	LH	.110	.179
NAND2, 2-Input NAND	HL	.159	.190
	LH	.186	.254
NOR2, 2-Input NOR	HL	.146	.171
	LH	.224	.303
DFF - CLK to Q	HL	.474	.647
	LH	.475	.613
LDL - CLK to Q	HL	.579	.766
	LH	.457	.671
Output Buffers			
OC33{25,33} N4_C	HL	4.649	4.155
	LH	6.711	5.793
OC33{25,33}N12_C	HL	3.125	2.937
	LH	3.875	3.519
Input Buffers			
IC33{25,33}_C	HL	.673	.573
	LH	.474	.667

Note:

1. All specifications in ns (typical). Output load capacitance is 50pF. Fanout loading for input buffers and gates is the equivalent of two gate input loads. For core cells and output buffers input slew is ~.2ns. For input buffer, input slew is 0.4ns (slew is measured from 30% - 70% of V_{DD}).

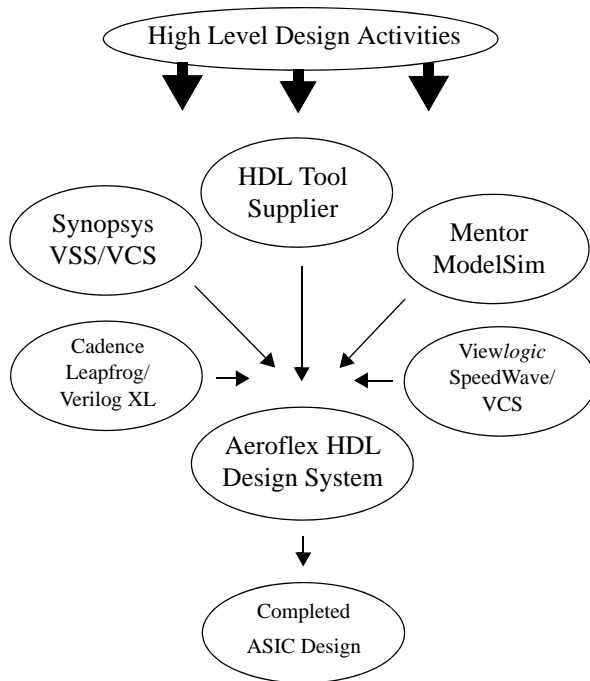
ASIC DESIGN SOFTWARE

Using a combination of state-of-the-art third-party and proprietary design tools, Aeroflex delivers the CAE support and capability to handle complex, high-performance ASIC designs from design concept through design verification and test.

Aeroflex's flexible circuit creation methodology supports high level design methodology by providing synthesis libraries in Liberty syntax. Compiled technology files are provided for Synopsys synthesis and design analysis tools. Design verification is performed in any VHDL or Verilog simulation environment, using Aeroflex's robust libraries. Aeroflex also supports Automatic Test Program Generation to improve design testing.

Aeroflex HDL DESIGN SYSTEMS

Aeroflex offers a Hardware Description Language (HDL) design system supporting VHDL and Verilog. Both the VHDL and Verilog libraries provide sign-off quality models and robust tools.



Aeroflex Springs HDL Design Flow

The VHDL libraries are VITAL 3.0 compliant, and the Verilog libraries are OVI 1.0 compliant. With the library capabilities Aeroflex provides, you can use High Level Design methods to synthesize your design for simulation. Aeroflex also provides tools to verify that your HDL design will result in working ASIC devices.

ADVANTAGES OF THE AEROFLEX HDL DESIGN SYSTEMS

- The Aeroflex HDL Design System gives you the freedom to use tools from Synopsys, Mentor Graphics, Cadence, Viewlogic, and other vendors to help you synthesize and verify a design.
- Aeroflex's Logic Rules Checker and Tester Rules Checker allow you to verify partial or complete designs for compliance with Aeroflex design rules.
- Aeroflex HDL Design System accepts back-annotation of timing information through SDF.

XDTsm (eXternal Design Translation)

Through Aeroflex's XDT services, customers can convert an existing non-Aeroflex design to Aeroflex's processes. The XDT tool is particularly useful for converting an FPGA to an Aeroflex radiation-tolerant gate array. The XDT translation tools convert industry standard netlist formats and vendor libraries to Aeroflex formats and libraries. Industry standard netlist formats supported by Aeroflex include:

- VHDL
- Verilog HDLTM
- FPGA source files (Actel, Altera, Xilinx)
- EDIF
- Third-party netlists supported by Synopsys

TOOLS SUPPORTED BY AEROFLEX

Aeroflex supports libraries for:

- Mentor Graphics
 - ModelSim
 - FastScan
- Synopsys
 - Design Compiler (with Power Compiler)
 - PrimeTime
 - PrimePower
 - Formality
 - TetraMax
- VITAL-compliant VHDL Simulation Tools
- OVI-compliant Verilog Tools

TRAINING AND SUPPORT

Aeroflex personnel conduct training classes tailored to meet individual needs. These classes can address a wide mix of engineering backgrounds and specific customer concerns. Applications assistance is also available through all phases of ASIC Design.

Physical Design

Using five layers of metal interconnect, Aeroflex achieves optimized layouts that maximize speed of critical nets, overall chip performance, and design density up to 3,000,000 equivalent gates.

Test Capability

Aeroflex supports all phases of test development from test stimulus generation through high-speed production test. This support includes ATPG, fault simulation, and fault grading. Scan design options are available on all UT0.25uHBD storage elements. Automatic test program development capabilities handle large vector sets for use with Aeroflex's LTX/Trillium MicroMaster, supporting high-speed testing (up to 80MHz with pin multiplexing), or Teradyne Tiger (up to 1.2GHz).

Unparalleled Quality and Reliability

Aeroflex is dedicated to meeting the stringent performance requirements of aerospace and defense systems suppliers. Aeroflex maintains the highest level of quality and reliability through our Quality Management Program under MIL-PRF-38535 and ISO- 9001. In 1988, we were the first gate array manufacturer to achieve QPL certification and qualification of our technology families. Our product assurance program has kept pace with the demands of certification and qualification.

Our quality management plan includes the following activities and initiatives.

- Quality improvement plan
- Failure analysis program
- SPC plan
- Corrective action plan
- Change control program
- Standard Evaluation Circuit (SEC) and Technology Characterization Vehicle (TCV) assessment program
- Certification and qualification program

Because of numerous product variations permitted with customer specific designs, much of the reliability testing is performed using a Standard Evaluation Circuit (SEC) and Technology Characterization Vehicle (TCV). Aeroflex utilizes the wafer foundry's data from TCV test structures to evaluate hot carrier aging, electromigration, and time dependent test samples for reliability testing.

Data from the wafer-level testing can provide rapid feedback to the fabrication process, as well as establish the reliability performance of the product before it is packaged and shipped.

Radiation Tolerance

Aeroflex incorporates radiation-tolerance techniques in process design, design rules, array design, power distribution, and library element design. All key radiation-tolerance process parameters are controlled and monitored using statistical methods and in-line testing.

PARAMETER	RADIATION HARDNESS ASSURANCE	NOTES
Total Ionizing Dose (TID)	1.0E5 rad(SiO ₂) 1.0E6 rad(SiO ₂)	1,2 1,3
Dose Rate Upset (DRU)	>6.6E9 rad(Si)/sec	4
Dose Rate Survivability (DRS)	No latchup observed to maximum dose rate of equipment configuration >4.8E11 rad(Si)/sec	5,8
Single Event Upset (SEU)	<1.2E-12 errors per cell-day	6,7
Single Event Latchup (SEL)	Latchup-immune over worst case 125°C, 2.75V or 3.6V core, 3.6V I/O V _{DD} . LET >108MeV/cm ² /mg	
Projected neutron fluence	1.0E14 n/sq cm	9

Notes:

1. Total dose Co-60 testing is in accordance with MIL-STD-883, Method 1019.
2. Data sheet electrical characteristics guaranteed to 3.0E5 rads(SiO₂) with on-chip RAM. All post-radiation values measured at 25°C.
3. Datasheet electrical characteristics guaranteed to 1.0E6 rad (SiO₂) with on-chip RAM. All post-radiation values measured at 25°C.
4. Short pulse 20ns FWHM (full width, half maximum) 25°C, 2.25V core/3.0V I/O V_{DD}.
5. Short pulse 35ns FWHM (full width, half maximum) 125°C, 2.75V core/3.6V I/O V_{DD}.
6. SEU limit based on standard evaluation circuit at 2.25V or 3.6V core/3.0V I/O V_{DD} 25°C condition.
7. SEU-hard flip-flop cell. Non-hard flip-flop typical is 8E-9.
8. Dose rate upset number may be different for a specific design due to the size of the ASIC die.
9. Based on George C. Messenger, "A Summary Review of Displacement Damage from High Energy Radiation in Silicon Semiconductors and Semiconductor Devices," IEEE Trans Nucl. Sci, vol. 39, no. 3, June 1992.

ABSOLUTE MAXIMUM RATINGS ¹

(Referenced to V_{SS})

SYMBOL	PARAMETER	LIMITS
V_{DD}^2	I/O DC Supply Voltage	-0.3V to 4.0V
V_{DDCORE}^2	Core DC Supply Voltage	-0.3 to 2.8V or -0.3 to 4.0V
$V_{DD} - V_{DDCORE}$	Max Voltage Difference (2.5V core)	3.6V
$V_{DDCORE} - V_{DD}$	Max Voltage Difference (2.5V core)	2.8V
T_{STG}	Storage temperature	-65°C to +150°C
T_J	Maximum junction temperature	+150°C
I_{LU}	Latchup immunity	+150mA
I_I	DC input current	+10mA
T_{LS}	Lead temperature (solder 5 sec)	+300°C

Note:

1. Stresses outside the listed absolute maximum ratings may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond limits indicated in the operational sections of this specification is not recommended. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
2. The recommended "power-on" sequence is V_{DDCORE} voltage supply applied first, followed by the V_{DD} voltage supply. The recommended "power-off" sequence is the reverse. Remove V_{DD} voltage supply, followed by removing V_{DDCORE} voltage supply.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS
$V_{DD}^{I/O}$	DC Supply Voltage	$3.3 \pm 0.3V$
V_{DDCORE}^{Core}	DC Supply Voltage	$2.5 \pm 0.25V$ or $3.3 \pm 0.3V$

Note:

1. Under normal conditions, V_{DD} must be maintained at a voltage greater than V_{DDCORE} by 0.25V for 2.5V core option.

DC ELECTRICAL CHARACTERISTICS

($V_{DD} = 3.3V \pm 0.3$; $V_{DDCORE} = 2.5V \pm 0.25$ or $3.3V \pm 0.3V$; $-55^{\circ}C < T_C < +125^{\circ}C$)

SYMBOL	PARAMETER	CONDITION	MIN	MAX	UNIT
V_{IL}	Low-level input voltage ¹ CMOS, OSC inputs PCI inputs	$V_{DD} = 3.3V \pm 0.3V$ $V_{DDCORE} = 2.5V \pm 0.25V$		$0.3 * V_{DD}$ $0.3 * V_{DD}$	V
V_{IH}	High-level input voltage ¹ CMOS inputs PCI inputs	$V_{DD} = 3.3V \pm 0.3$ $V_{DDCORE} = 2.5V \pm 0.25$	$0.7 * V_{DD}$ $0.5 * V_{DD}$		V
V_{IL}	Low-level input voltage SSTL inputs	$V_{DDSTL} = 1.8V + 10\%$ $V_{REF} = 0.9V$	$V_{REF} - 0.125$		V
V_{IH}	High-level input voltage SSTL inputs	$V_{DDSTL} = 1.8V + 10\%$ $V_{REF} = 0.9v$		$V_{REF} + 0.125$	V
V_{T+}	Schmitt Trigger, positive going threshold ¹	$V_{DD} = 3.3V \pm 0.3$ $V_{DDCORE} = 2.5V \pm 0.25$		$0.7 * V_{DD}$	V
V_{T-}	Schmitt Trigger, negative going threshold ¹	$V_{DD} = 3.3V \pm 0.3$ $V_{DDCORE} = 2.5V \pm 0.25$	$0.3V_{DD}$		V
V_H	Schmitt Trigger, typical range of hysteresis ²		0.4		V
I_{IN}	Input leakage current CMOS and Schmitt inputs Inputs with pull-down resistors Inputs with pull-down resistors Inputs with pull-up resistors Inputs with pull-up resistors Cold Spare Inputs - Off Cold Spare Inputs - On	$V_{IN} = V_{DD}$ or V_{SS} $V_{IN} = V_{DD}$ $V_{IN} = V_{SS}$ $V_{IN} = V_{SS}$ $V_{IN} = V_{DD}$ $V_{IN} = 0$ to $3.6V$ $V_{IN} = V_{DD}$ or V_{SS}	-1 10 -5 -120 -5 -5	1 120 5 -10 5 5	μA
V_{OL}	Low-level output voltage ³ CMOS/LVTTL 4.0mA buffer CMOS/LVTTL 8.0mA buffer CMOS/LVTTL 12.0mA buffer CMOS/LVTTL 24.0mA buffer CMOS outputs (optional) CMOS outputs (optional) PCI outputs	$I_{OL} = 4.0mA$ $I_{OL} = 8.0mA$ $I_{OL} = 12.0mA$ $I_{OL} = 24.0mA$ $I_{OL} = 1.0\mu A$ $I_{OL} = 100.0\mu A$ $I_{OL} = 1500.0\mu A$		0.4 0.4 0.4 0.4 0.05 0.25 $0.1 * V_{DD}$	V

SYMBOL	PARAMETER	CONDITION	MIN	MAX	UNIT
V _{OH}	High-level output voltage ³ CMOS/LVTTL 4.0mA buffer CMOS/LVTTL 8.0mA buffer CMOS/LVTTL 12.0mA buffer CMOS/LVTTL 24.0mA buffer CMOS outputs (optional) CMOS outputs (optional) PCI outputs	I _{OH} = -4.0mA I _{OH} = -8.0mA I _{OH} = -12.0mA I _{OH} = -24.0mA I _{OH} = -1.0μA I _{OH} = -100.0μA I _{OH} = -500.0μA	2.4 2.4 2.4 2.4 V _{DD} -0.05 V _{DD} -0.35 0.9* V _{DD}		V
V _{OL}	Low-level output voltage SSTL outputs	V _{DDSTL} = 1.8V - 10% I _{OL} = 12mA		0.7	V
V _{OH}	High-level output voltage SSTL outputs	V _{DDSTL} = 1.8V - 10% I _{OL} = -12mA	V _{DDSTL} - 0.5		V
I _{OZ}	Three-state output leakage current CMOS Cold Spare Inputs - Off Cold Spare Inputs - On	V _O = V _{DD} and V _{SS} V _{IN} = 0V and 3.6V V _{DD} = V _{SS} = 0 V _{DD} = V _{DD} = V _{SS}	-5 -10 -10	5 +10 +10	μA
I _{OS}	Output short-circuit current ^{2,4}	V/OUT= I/O drive = 4mA I/O drive = 8mA I/O drive = 12mA I/O drive = PCI V/OUT= I/O drive = 4mA I/O drive = 8mA I/O drive = 12mA I/O drive = PCI	3.0V@125°C 68mA 95mA 174mA 410mA 3.6V@-55°C -84mA -102mA -153mA -348mA	3.6V@-55°C 143mA 204mA 340mA 764mA 3.0V@125°C -30mA -47mA -92mA -230mA	mA
C _{IN}	Input capacitance ⁵ LVDS inputs SSTL inputs	f = 1MHz @ 0V	4	15 16 15	pF
C _{OUT}	Output capacitance ⁵ 4.0mA buffer 8.0mA buffer 12.0mA buffer 24.0mA buffer LVDS outputs SSTL outputs	f = 1MHz @ 0V		15 18 20 25 19 15	pF

C_{IO}	Bidirect I/O capacitance ⁵ 4.0mA buffer 8.0mA buffer 12.0mA buffer PCI bidirects	$f = 1\text{MHz @ } 0\text{V}$		15 18 25 13	pF
V_{OD1}	Differential output voltage LVDS	$R_L = 100\Omega$	250	800	mV
V_{OS}	Offset voltage LVDS	$R_L = 100\Omega$	1.12	1.6	V
ΔV_{OD1}	Change in magnitude of V_{OD1} for complementary output states LVDS	$R_L = 100\Omega$		35	mV
ΔV_{OS1}	Change in magnitude of V_{OS1} for complementary output states LVDS	$R_L = 100\Omega$		25	mV
IOS LVDS	Output short circuit current LVDS	$V_{IN} = V_{DD}, V_{OUT+} = 0\text{V}$ or $V_{IN} = \text{GND}, V_{OUT-} = 0\text{V}$		9.0	mA
I_{DDQ}	Quiescent Supply Current ⁶ Group A, subgroups 1,3	$V_{DD} = 3.6\text{V}$ 200K gates 400K gates 600K gates 800K gates 1000K gates 1500K gates 2000K gates 2500K gates 3000K gates			50 100 150 200 250 375 500 625 750
	Group A, subgroup 2	$V_{DD} = 3.6\text{V}$ 200K gates 400K gates 600K gates 800K gates 1000K gates 1500K gates 2000K gates 2500K gates 3000K gates			1 2 3 4 5 7.5 10 12.5 15
	Group A, subgroup 1 RHA Designator: M, D, P, L, R	$V_{DD} = 3.6\text{V}$ 200K gates 400K gates 600K gates 800K gates 1000K gates 1500K gates 2000K gates 2500K gates 3000K gates			4 6 8 10 12 18 24 30 36

Notes:

1. Functional tests are conducted in accordance with MIL-STD-883 with the following input test conditions: $V_{IH} = V_{IH(min)} + 20\%$, $- 0\%$; $V_{IL} = V_{IL(max)} + 0\%$, $- 50\%$, as specified herein, for TTL, CMOS, or Schmitt compatible inputs. Devices may be tested using any input voltage within the above specified range, but are guaranteed to $V_{IH(min)}$ and $V_{IL(max)}$.
2. Supplied as a design limit but not guaranteed or tested.
3. Per MIL-PRF-38535, for current density $\leq 5.0E5$ amps/cm², the maximum product of load capacitance (per output buffer) times frequency should not exceed 3,765pF*MHz.
4. Aeroflex IOS specification - maximum of 1 second for any output to be shorted to ground or the maximum output voltage supply - exceeding this specification will reduce the DC current lifetime because of potential joule heating.
5. Capacitance measured for initial qualification and when design changes may affect the value. Capacitance is measured between the designated terminal and V_{SS} at frequency of 1MHz @0V and a signal amplitude of ≤ 50 mV RMS in a 144 CPGA package.
6. All inputs with internal pull-ups should be left floating. All other inputs should be tied high or low.

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Aeroflex Colorado Springs - Datasheet Definition

Advanced Datasheet - Product In Development

Preliminary Datasheet - Shipping Prototype

Datasheet - Shipping QML & Reduced Hi-Rel

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